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Application Number	10564563
Filing Date	2008-01-25
First Named Inventor	Houjin Huang
Art Unit	3742
Examiner Name	Geoffrey S. Evans
Attorney Docket Number	09792909-6573

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1	HOUJIN HUANG, et al., "Large-Scale Rooted Growth of Aligned Super Bundles of Single-Walled Carbon Nanotubes Using a Directed Arc Plasma Method", Chemical Physics Letters, July 2001, Vol. 343, pp. 7-14	<input type="checkbox"/>
2	HOUJIN HUANG, et al., "High Quality Double-Walled Carbon Nanotube Super Bundles Grown in a Hydrogen-Free Atmosphere", J. Phys. Chem. B, July 2003, Vol. 107, No. 34, pp. 8794-8798.	<input type="checkbox"/>
3	H.W. ZHU, et al., "Direct Synthesis of Long Single-Walled Carbon Nanotube Stands", SCIENCE, May 2002, Vol. 296, pp. 884-886	<input type="checkbox"/>
4	HOUJIN HUANG, et al., "Metal Sulfide Catalyzed Growth of Carbon Nanofibers and Nanotubes", Carbon, February 2003, Vol. 41, No. 3, pp. 615-618	<input type="checkbox"/>
5	HOUJIN HUANG, et al., Improved Oxidation Resistance of Single-Walled Carbon Nanotubes Produced by Arc Discharge in a Bowl-Like Cathode", Nano Letters, October 2002, Vol. 2, No. 10, pp. 1117-1119.	<input type="checkbox"/>

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